NSN 5961-01-069-7726

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-069-7726 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.275 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.105 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: D07-1 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 15.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 150.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** 21 nov 00; girder project, zg non-concur to cancellation action; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No